捷多邦,专业PCB打样工厂,24小时加急出货 查询BCR25KM-12LB供应商 RENESA BCR25KM-12LB Triac Medium Power Use REJ03G1676-0100 Rev.1.00 Jun 05, 2008 WWW.DZS **Features** I<sub>T (RMS)</sub>: 25 A Insulated Type • V<sub>DRM</sub>: 600 V Planar Type I<sub>FGTI</sub>, I<sub>RGTI</sub>, I<sub>RGTIII</sub>: 50 mA V<sub>iso</sub>: 2000 V **Outline** RENESAS Package code: PRSS0003AB-A (Package name: TO-220FN) T<sub>1</sub> Terminal
 T<sub>2</sub> Terminal 3. Gate Terminal 3 Applications

Contactless AC switch, electric heater control, light dimmer, on/off and speed control of small induction motor, on/off control of copier lamp

# **Maximum Ratings**

Parameter	Symbol	Voltage class	Unit	
	Oymbol	12		
Repetitive peak off-state voltage Note1	V <sub>DRM</sub>	600	V	
Non-repetitive peak off-state voltage Note1	V <sub>DSM</sub>	720	V	

Notes: 1. Gate open.



### BCR25KM-12LB

Parameter	Symbol	Ratings	Unit	Conditions		
RMS on-state current	I <sub>T (RMS)</sub>	25	A	Commercial frequency, sine full wave 360° conduction, Tc = 62°C		
Surge on-state current	I <sub>TSM</sub>	250	A	50 Hz sinewave 1 full cycle, peak value, non-repetitive		
I <sup>2</sup> t for fusion	l <sup>2</sup> t	313	A <sup>2</sup> s	Value corresponding to 1 cycle of half wave 50Hz, surge on-state current		
Peak gate power dissipation	P <sub>GM</sub>	5	W			
Average gate power dissipation	P <sub>G (AV)</sub>	0.5	W			
Peak gate voltage	V <sub>GM</sub>	10	V			
Peak gate current	I <sub>GM</sub>	2	А			
Junction Temperature	Tj	-40 to +150	°C			
Storage temperature	Tstg	-40 to +150	°C			
Mass	_	2.0	g	Typical value		
Isolation voltage	V <sub>iso</sub>	2000	V	Ta = 25°C, AC 1 minute,		
				$T_1 \bullet T_2 \bullet G$ terminal to case		

# **Electrical Characteristics**

Parameter		Symbol	Min.	Тур.	Max.	Unit	Test conditions
Repetitive peak off-state current		I <sub>DRM</sub>	—	_	3.0/5.0	mA	Tj = $125/150^{\circ}$ C, V <sub>DRM</sub> applied
On-state voltage		V <sub>TM</sub>	—	_	1.5	V	$Tc = 25^{\circ}C$ , $I_{TM} = 40$ A, instantaneous measurement
Gate trigger voltage <sup>Note2</sup>	Ι	$V_{FGTI}$	—	_	2.0	V	$Tj = 25^{\circ}C, V_{D} = 6 V, R_{L} = 6 \Omega,$
	II	V <sub>rgti</sub>	—	_	2.0	V	R <sub>G</sub> = 330 Ω
	III	V <sub>RGTIII</sub>	—	_	2.0	V	
Gate trigger curent <sup>Note2</sup>	Ι	I <sub>FGTI</sub>	—	_	50	mA	$Tj = 25^{\circ}C, V_D = 6 V, R_L = 6 \Omega,$
	II	I <sub>RGTI</sub>	—	_	50	mA	R <sub>G</sub> = 330 Ω
	III	I <sub>RGTIII</sub>	—		50	mA	
Gate non-trigger voltage		$V_{GD}$	0.2/0.1	_	_	V	$Tj = 125/150^{\circ}C, V_D = 1/2 V_{DRM}$
Thermal resistance		R <sub>th (j-c)</sub>	—	_	2.8	°C/W	Junction to case <sup>Note3</sup>
Critical-rate of rise of off-state commutation voltage <sup>Note4</sup>		(dv/dt)c	10/1	_	—	V/µs	Tj = 125/150°C

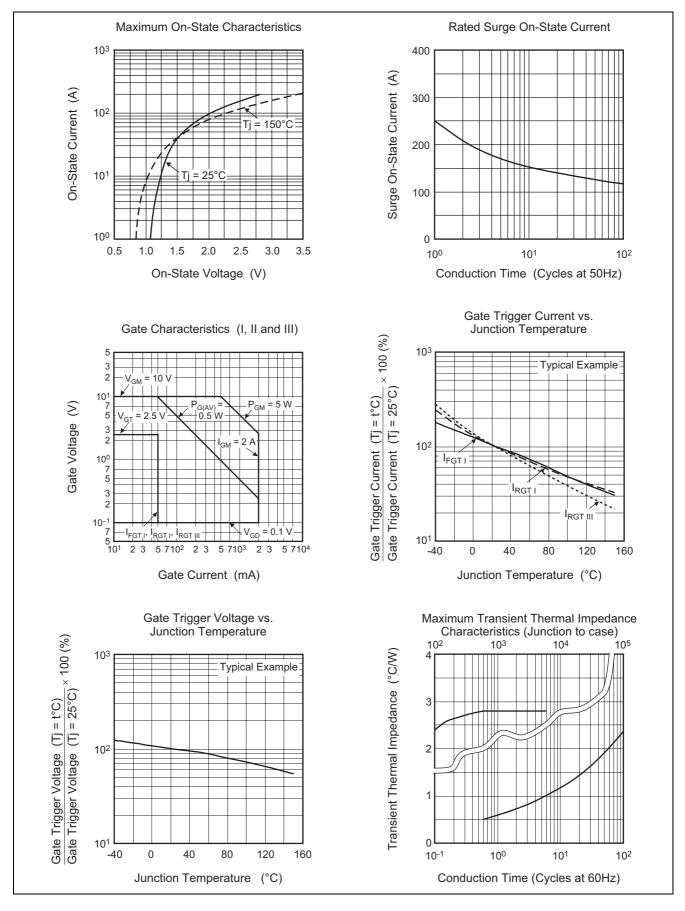
Notes: 2. Measurement using the gate trigger characteristics measurement circuit.

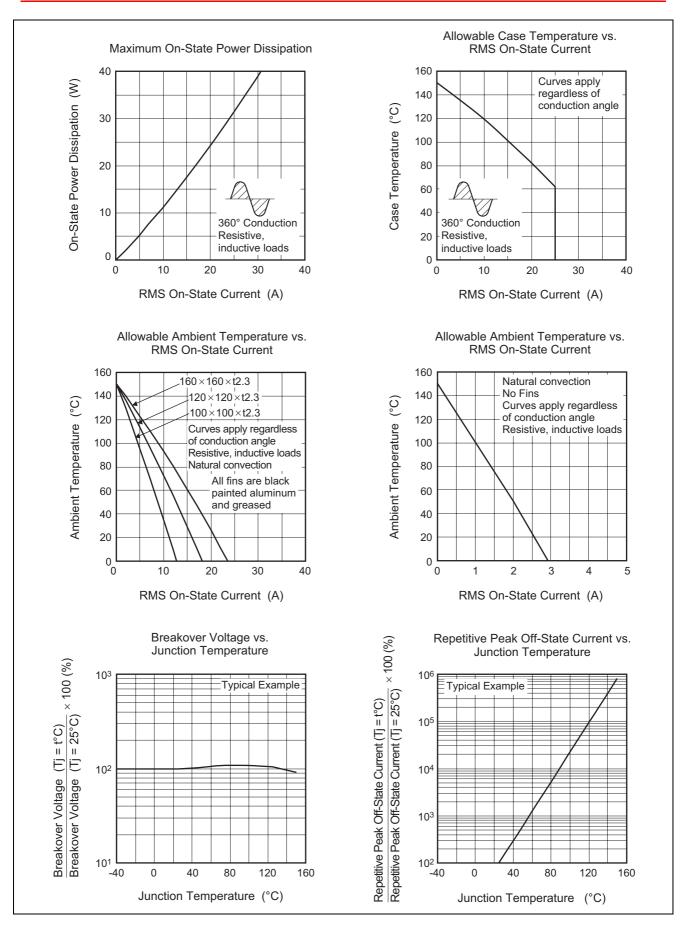
3. The contact thermal resistance  $R_{th\,(c\text{-}f)}$  in case of greasing is 0.5°C/W.

4. Test conditions of the critical-rate of rise of off-state commutation voltage is shown in the table below.

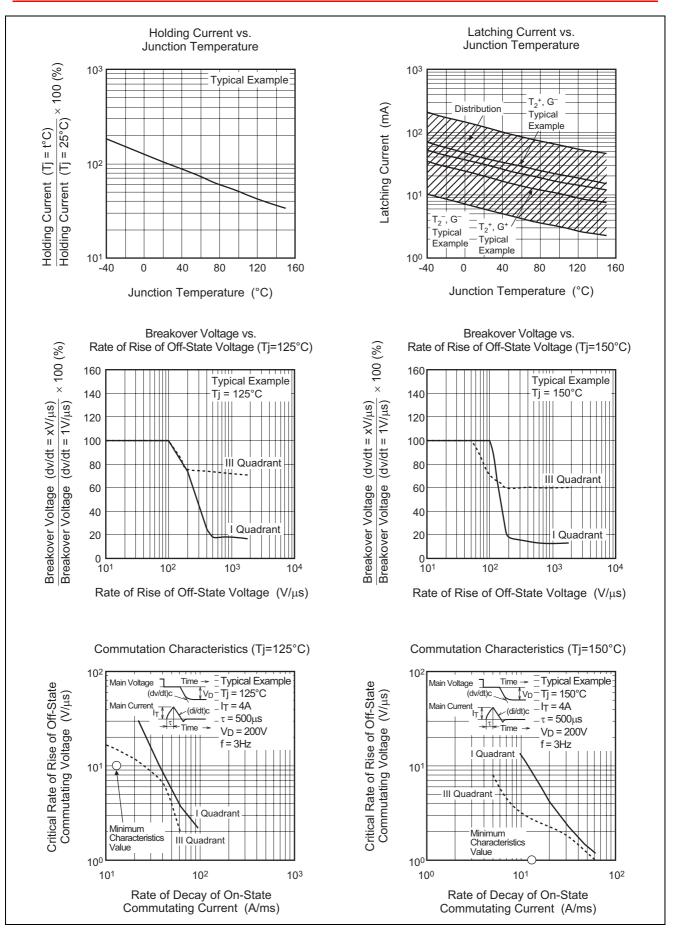
Test conditions	Commutating voltage and current waveforms (inductive load)		
1. Junction temperature Tj = 125/150°C	Supply Voltage → Time		
<ol> <li>Rate of decay of on-state commutating current (di/dt)c = -13 A/ms</li> </ol>	Main Current → Time		
3. Peak off-state voltage V <sub>D</sub> = 400 V	Main VoltageTime (dv/dt)cV		

## **Performance Curves**

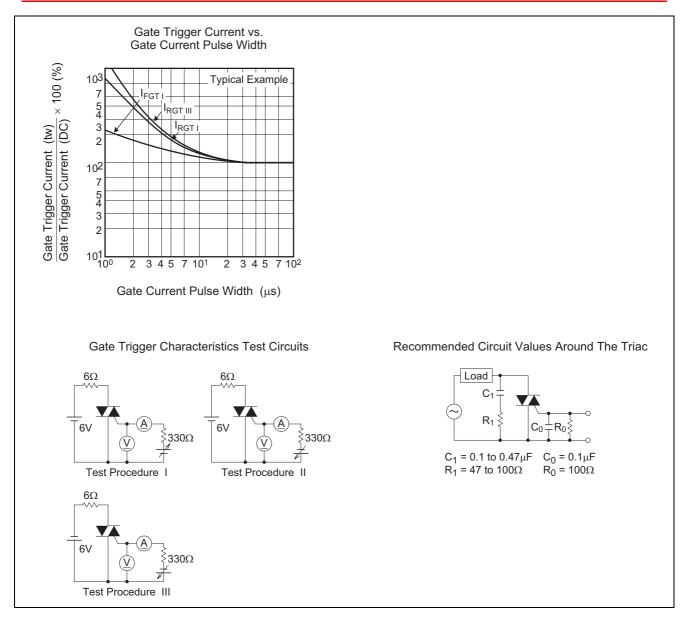




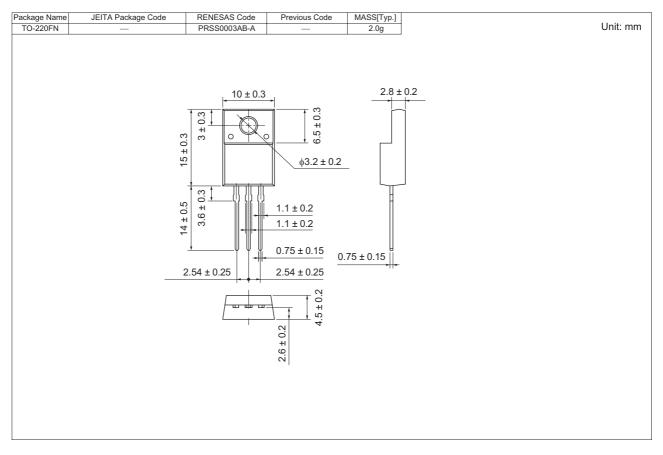
### BCR25KM-12LB



## BCR25KM-12LB



# **Package Dimensions**



## **Order Code**

Lead form	Standard packing	Quantity	Standard order code	Standard order code example
Straight type	Plastic Magazine (Tube)	50	Type name	BCR25KM-12LB
Lead form	Plastic Magazine (Tube)	50	Type name – Lead forming code	BCR25KM-12LB -A8

Note : Please confirm the specification about the shipping in detail.

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